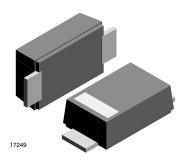


Vishay Semiconductors

Standard Recovery Rectifier, High Voltage Surface Mount



MECHANICAL DATA

Case: DO-219AB (SMF)

Polarity: band denotes cathode end

Weight: approx. 15 mg
Packaging codes/options:

18/10K per 13" reel (8 mm tape), 50K/box 08/3K per 7" reel (8 mm tape), 30K/box

Int. construction: Single

FEATURES

- · For surface mounted applications
- · Low profile package
- Ideal for automated placement
- · Glass passivated
- High temperature soldering: 260 °C/10 s at terminals
- Wave and reflow solderable
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>





ROHS COMPLIANT HALOGEN FREE

PARTS TABLE					
PART	ORDERING CODE	MARKING	REMARKS		
S1FLB-M	S1FLB-M-18 or S1FLB-M-08	НВ	Tape and reel		
S1FLD-M	S1FLD-M-18 or S1FLD-M-08	HD	Tape and reel		
S1FLG-M	S1FLG-M-18 or S1FLG-M-08	HG	Tape and reel		
S1FLJ-M	S1FLJ-M-18 or S1FLJ-M-08	HJ	Tape and reel		
S1FLK-M	S1FLK-M-18 or S1FLK-M-08	HK	Tape and reel		
S1FLM-M	S1FLM-M-18 or S1FLM-M-08	HM	Tape and reel		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT		
		S1FLB-M	V_{RRM}	100	V		
		S1FLD-M	V_{RRM}	200	V		
Manian and a state of the state		S1FLG-M	V_{RRM}	400	V		
Maximum repetitive peak reverse voltage		S1FLJ-M	V_{RRM}	600	V		
		S1FLK-M	V_{RRM}	800	V		
		S1FLM-M	V_{RRM}	1000	V		
		S1FLB-M	V_{RMS}	70	V		
		S1FLD-M	V_{RMS}	140	V		
Maximum DMC valtage		S1FLG-M	V_{RMS}	280	V		
Maximum RMS voltage		S1FLJ-M	V_{RMS}	420	V		
		S1FLK-M	V_{RMS}	560	V		
		S1FLM-M	V_{RMS}	700	V		
		S1FLB-M	V_{DC}	100	V		
Marian as DO blastica saltana		S1FLD-M	V_{DC}	200	V		
		S1FLG-M	V_{DC}	400	V		
Maximum DC blocking voltage		S1FLJ-M	V_{DC}	600	V		
		S1FLK-M	V_{DC}	800	V		
		S1FLM-M	V_{DC}	1000	V		
	$T_{tp} = 75 ^{\circ}\text{C}^{(1)}$		I _{F(AV)}	1.5	Α		
Maximum average forward rectified current	$T_A = 25 ^{\circ}\text{C}^{(1)}$ at $R_{thJA} < 110 \text{K/W}$		I _{F(AV)}	1	Α		
	$T_A = 65 ^{\circ}C^{(1)}$		I _{F(AV)}	0.7	Α		
Peak forward surge current 8.3 ms half sine-wave	T _L = 25 °C		I _{FSM}	22	Α		

Note

⁽¹⁾ Averaged over any 20 ms periode



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THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Thermal resistance junction to ambient air (1)		R _{thJA}	180	K/W			
Operating junction and storage temperature range		T _j , T _{stg}	- 55 to + 150	°C			

Note

⁽¹⁾ Mounted on epoxy substrate with 3 mm x 3 mm Cu pads (≥ 40 µm thick)

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	1 A ⁽¹⁾	S1FLB-M	V _F			1.1	V
		S1FLD-M	V_{F}			1.1	V
Lasterna of Community allows		S1FLG-M	V_{F}			1.1	V
Instaneous forward voltage		S1FLJ-M	V_{F}			1.1	V
		S1FLK-M	V_{F}			1.1	V
		S1FLM-M	V_{F}			1.1	V
	T _A = 25 °C	S1FLB-M	I _R			10	μΑ
		S1FLD-M	I _R			10	μΑ
		S1FLG-M	I _R			10	μΑ
		S1FLJ-M	I _R			10	μΑ
		S1FLK-M	I _R			10	μΑ
Maximum DC reverse current at rated		S1FLM-M	I _R			10	μΑ
DC blocking voltage	T _A = 125 °C	S1FLB-M	I _R			50	μΑ
		S1FLD-M	I _R			50	μΑ
		S1FLG-M	I _R			50	μΑ
		S1FLJ-M	I _R			50	μΑ
		S1FLK-M	I _R			50	μΑ
		S1FLM-M	I _R			50	μΑ
	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A	S1FLB-M	t _{rr}			1800	ns
		S1FLD-M	t _{rr}			1800	ns
Deviana na accesa tima		S1FLG-M	t _{rr}			1800	ns
Reverse recovery time		S1FLJ-M	t _{rr}			1800	ns
		S1FLK-M	t _{rr}			1800	ns
		S1FLM-M	t _{rr}			1800	ns
		S1FLB-M	C _j		4		pF
	4 V, 1 MHz	S1FLD-M	Cj		4		pF
Tymical canacitanae		S1FLG-M	C _j	_	4		pF
Typical capacitance		S1FLJ-M	C _j		4		pF
		S1FLK-M	Cj		4		pF
		S1FLM-M	C _i		4		рF

Note
(1) Pulse test: 300 µs pulse width, 1 % duty cycle

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

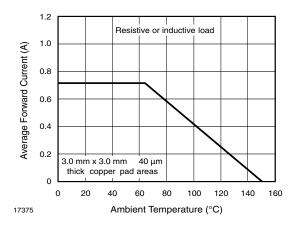


Fig. 1 - Forward Current Derating Curve

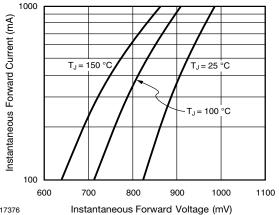


Fig. 2 - Typical Instantaneous Forward Characteristics

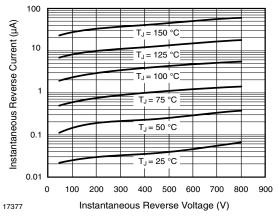


Fig. 3 - Typical Instantaneous Reverse Characteristics

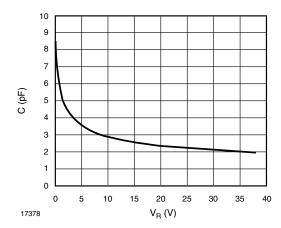
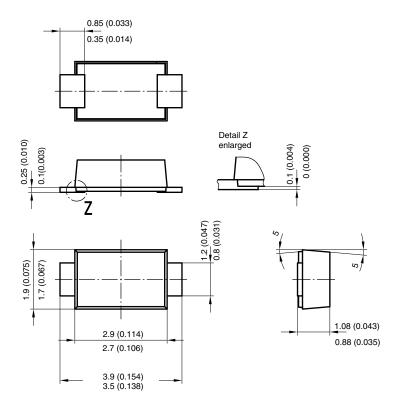


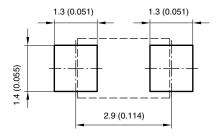
Fig. 4 - Capacitance vs. Reverse Voltage

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PACKAGE DIMENSIONS in millimeters (inches): DO-219AB (SMF)



Foot print recommendation:

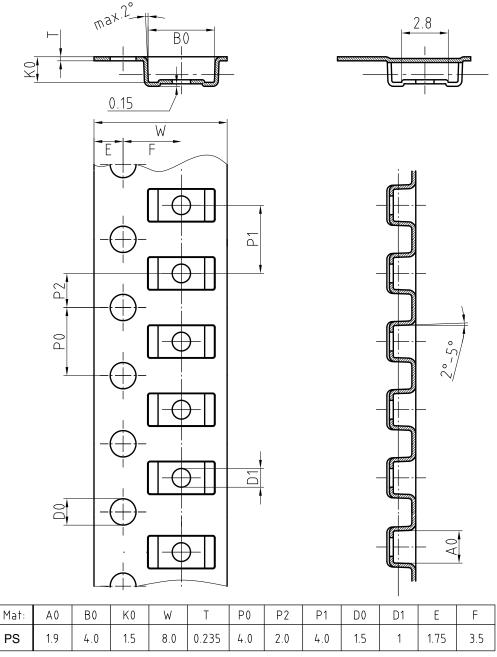


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BLISTERTAPE DIMENSIONS in millimeters: **DO-219 AB (SMF)**

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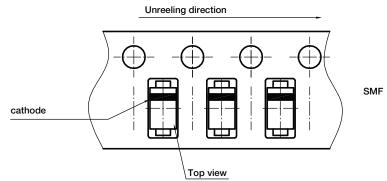


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Vishay Semiconductors

ORIENTATION IN CARRIER TAPE - SMF



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